

December 1997

Product Reliability Report

This report presents the product reliability data for Maxim's analog products. The data was acquired from extensive reliability stress testing performed in 1996. It is separated into seven fabrication processes: 1) Standard Metal-Gate CMOS (SMG); 2) Medium-Voltage Metal-Gate CMOS (MV1); 3) Medium-Voltage Silicon-Gate CMOS (MV2); 4) 3µm Silicon-Gate CMOS (SG3); 5) 5µm Silicon-Gate CMOS (SG5); 6) 1.2µm Silicon-Gate CMOS; and 7) Bipolar (BIP) processes.

Over 8,967,000 device hours have been accumulated for products stressed at an elevated temperature (135°C) during this period. The data in this report is considered typical of Maxim's production. As you will see, Maxim's products demonstrate consistently high reliability.



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Fabrication Processes

Maxim is currently running the following seven major fabrication processes:

SMG (Standard Metal-Gate CMOS)

MV1 (Medium-Voltage Metal-Gate CMOS)

MV2 (Medium-Voltage Silicon-Gate CMOS)

SG3 (3-Micron Silicon-Gate CMOS)

SG5 (5-Micron Silicon-Gate CMOS)

SG1.2 (1.2-Micron Silicon-Gate CMOS)

Bipolar (18/12-Micron)

SMG

SMG is a 6-micron, 24V, metal-gate CMOS process. It has conservative design rules, but is appropriate for many SSI and MSI circuit designs. This very popular fabrication process is used to produce many of Maxim's products.

MV1

MV1 is a 12-micron, 44V, metal-gate CMOS process, used exclusively to produce our analog switch product line.

MV2

MV2 is a 5-micron, 44V, silicon-gate CMOS process, also used in our analog switch production line.

SG3, SG5, and SG1.1

SG3 is a 3-micron, 12V, silicon-gate CMOS process. SG5 is a 5-micron, 20V, silicon-gate CMOS process. SG1.2 is a 1.2-micron, 6V, silicon-gate CMOS process. SG3, SG5, and SG1.2 have become our future process standards.

Bipolar

Bipolar is an 18-micron, 44V or 12-micron, 24V bipolar process, used chiefly for precision references, op amps, and A/D converters.

Reliability Methodology

Maxim's quality approach to reliability testing is conservative. Each of the seven fabrication processes has been qualified using the following industry-standard tests: Life Test, 85/85, Pressure Pot, HAST, High-Temperature Storage Life, and Temperature Cycling (Table 1). Each process has been qualified and proven to produce inherently high-quality product.

Maxim's early conservative approach included burn-in as a standard stage of our production flow.

Burn-in ensured that our customers were receiving a quality product. Now, with the addition of our own sophisticated fabrication facility, we have improved the innate product quality to the point where burnin adds little reliability value.

Each time a new fabrication process is introduced at Maxim, an Infant Mortality evaluation (burn-in evaluation) is initiated at the same time as process qualification. Through this Infant Mortality evaluation we can identify fabrication process defects at an early stage of production. Using the data in Table 2 (Infant Mortality Evaluation Results) and Figure 9 (Infant Mortality Pareto Chart) we can identify which category should next be improved. The data shown demonstrates the positive direction of Maxim's quality standards. It illustrates our continued dedication to providing the lowest overall-cost solution to our customers, through superior quality products.

Maxim's SMG, MV1, MV2, SG3, SG5, SG1.2, and Bipolar processes clearly meet or exceed the performance and reliability expectations of the semiconductor industry. These processes are qualified for production. Cross-sectional views of these seven processes are shown in Figures 1–7.

TEST NAME	CONDITIONS	SAMPLING PLAN ACC/SS
Life Test	+135°C/1000 hrs.	1/77
85/85	+85°C, 85% R.H., 1000 hrs. with Bias	1/77
Pressure Pot	+121°C, 100% R.H., 2 ATM, 168 hrs.	0/77
Temperature Cycling	-65°C to +150°C Air-to-Air/1000 Cycling	1/77
High-Temp. Storage Life	+150°C/1000 hrs.	1/77

Maxim has implemented a series of Quality and Reliability programs aimed at building the highest quality, most reliable analog products in the industry.

Reliability Program Steps

All products, processes, packages, and changes in

(1) SMG	(Refer to Figure 1)		(5) SG5	(Refer to Figure 5)	
Layer	Description	Dimension	Layer	Description	Dimension
1	P-Well Diffusion	10μm	1	P-Well Diffusion	8µm
2	P+ Diffusion	2µm	2	PNP Base Drive	
3	N+ Diffusion	2µm	3	Zener Implant	
4	Gate-Oxide Growth	900Å	4	Active Area/Field Ox	1μm
5	Threshold Implant		5	N Guard	
6	Contact Etch		6	P Guard	
7	Metallization	1μm (Al, Si-1%)	7	Threshold Adjust	%
8	Passivation	$0.8 \mu m (Si_3 N_4 \text{ over SiO}_2)$	8	Gate-Oxide Growth	750Å
(2) MV1	(Refer to Figure 2)		9	Polysilicon 1	4400Å 1000Å
Layer	Description	Dimension	10 11	Cap Oxide Polysilicon 2	4400Å
0	Buried Layer		12	N+ Implant (Source/Drain)	4400A
1	EPI Deposit	10μm 19μm	13	P+ Implant (Source/Drain)	
2	P-Well Diffusion	10μm	14	Chrome/Si Thin-Film Deposi	†
3	P+ Diffusion	3µm	15	Contact	
4	N+ Diffusion	3µm	16	Metallization	1μm
5	Gate-Oxide Growth	1 ⁹ 75Å	17	Passivation	0.8µm (Si ₃ N ₄ over SiO ₂)
6	Threshold Implant		(6) SC1	2 (Defer to Figure 6)	
7	Contact			.2 (Refer to Figure 6)	B: .
8	Metallization	1μm (Al, Si-1%)	Layer	Description	Dimension
9	Passivation	$0.8\mu m (Si_3N_4 \text{ over SiO}_2)$	0	Mark Layer on P Substrate	
(3) MV2	(Refer to Figure 3)		1	N+ Buried Layer	4µm
Layer	Description	Dimension	2	P+ Buried Layer P Well	6µm
1	Buried Layer		4	NPN Base	2.8µm
2	P Well	24.0μm 10.0μm	5	PNP Base	
3	P+ Diffusion	1.5µm	6	Active Area	
4	N+ Diffusion	1.5µm	7	P Guard	
5	Gate-Oxide Growth	1000Å	8	N Guard	
6	P-Ch Threshold Adjust		9	Gate-Oxide Growth	230Å
7	Polysilicon	4500Å	10	Poly 1	4200Å
8	NLDD		11	Poly 2	4200Å
9	PLDD		12	NMOS LDD	0.2
10	N+ Ohmic		13 14	N+ Implant (Source/Drain) P+ Implant (Source/Drain)	0.3µm
11 12	Contact	1 0um	15	Thin Film (Chrome/Si)	0.3µm
13	Metal Passivation	1.0µm 0.8µm	16	Contact	
13	i assivation	ο.ομπ	17	TF Contact	
(4) SG3	(Refer to Figure 4)		18	Metal 1	6000Å
Layer	Description	Dimension	19	Metal 1 Options	
1	P Well	6.0µm	20	Via	
2	PNP Base	·	21	Metal 2	1.0µm
3	Zener Implant		22	Passivation	8000Å
4	Active Area	1.5µm	(7) BIP	(Refer to Figure 7)	
5	P Guard		Layer	Description	Dimension
6	N Guard		1	N+ Buried Layer	
7	P-Ch Threshold Adjust	7000 Å	2	P+ Isolation	4.5μm 20μm
8 9	Poly 2 Poly 1	7000Å 4000Å	3	P Base	3μm
10	N+ Block	4000A	4	N+ Emitter	2.5µm
11	P+ Select		5	Capacitor	1500Å
12	Thin Film		6	Contact Etch	
13	CrSi Contact		7	Aluminum	11kÅ (Al, Si-1%)
14	Contact		8	Passivation	8kÅ (Si ₃ N ₄ over SiO ₂)
15	Metal	1.0µm			
16	Passivation	0.8µm (Si ₃ N ₄ over SiO ₂)			

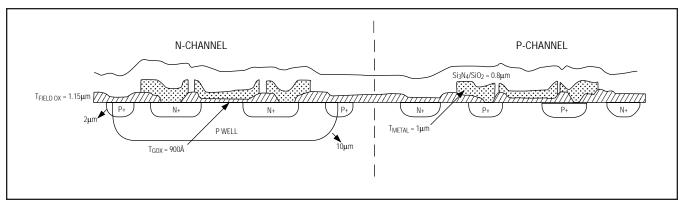


Figure 1. SMG Process

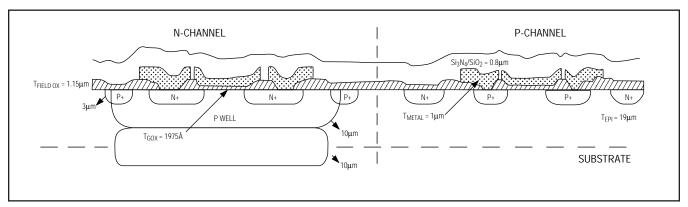


Figure 2. MV1 Process

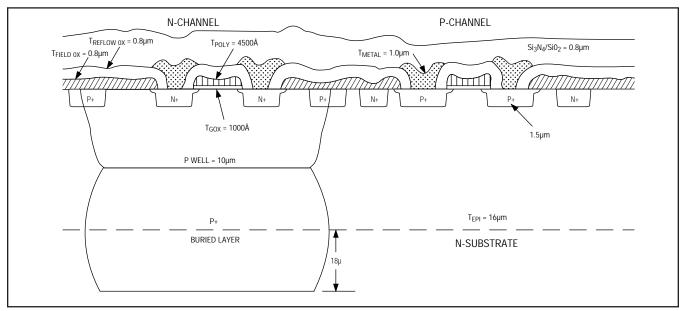


Figure 3. MV2 Process

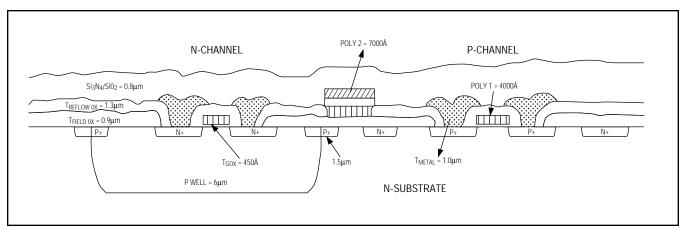


Figure 4. SG3 Process

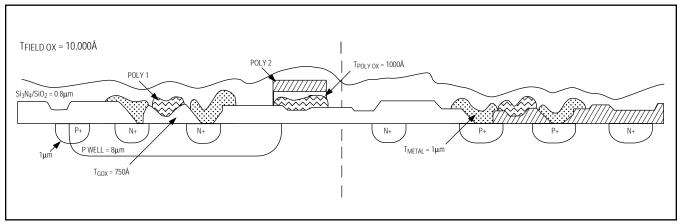


Figure 5. SG5 Process

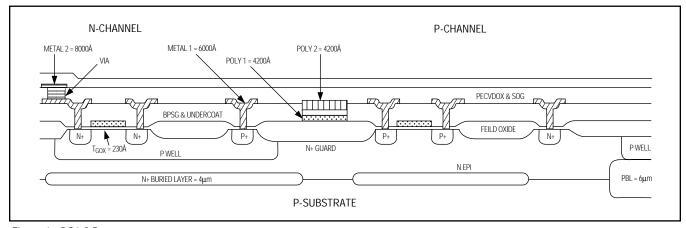


Figure 6. SG1.2 Process

6 ______*MA*XI*M*

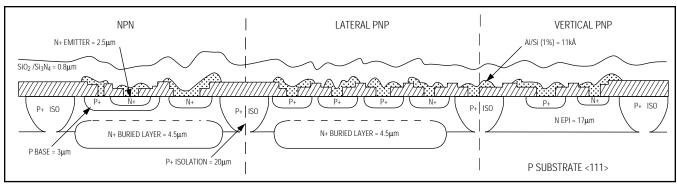


Figure 7. Bipolar Process

manufacturing steps must be subjected to Maxim's reliability testing before release to manufacturing for mass production. Our reliability program includes the following steps:

Step 1: Initial Reliability Qualification ProgramStep 2: Ongoing Reliability Monitor Program

Step 3: In-Depth Failure Analysis and Corrective Action

Tables 5–11 show the results of long-term Life Tests by process and device type. Tables 12–16 show the results of the 85/85, Pressure Pot, HAST, Temperature Cycling, and High-Temperature Storage Life tests, by device type. Tables 17 and 18 show hybrid product reliability.

Step 1: Initial Reliability Qualification Program

Maxim's product reliability test program meets EIA-JEDEC standards and most standard OEM reliability test requirements.

Table 1 summarizes the qualification tests that are part of Maxim's reliability program. Before releasing products, we require that three consecutive manufacturing lots from a new process technology successfully meet the reliability test requirements.

Step 2: Ongoing Reliability Monitor Program

Each week Maxim identifies three wafer lots per process per fab to be the subjects of reliability monitor testing. Each lot is Pressure Pot tested, and tested to 192 hours of High-Temperature Life (at 135°C). On a quarterly basis, one wafer lot per process per fab is identified and subjected to the same long-term reliability tests as defined in **Table 1**. Test results are fed back into production.

Step 3: In-Depth Failure Analysis and Corrective Action

Our technical failure-analysis staff is capable of analyzing every reliability test failure to the device level. If an alarming reliability failure mechanism or trend is identified, the corrective action is initiated automatically. This proactive response and feedback ensures that discrepancies in any device failure mechanism are corrected before becoming major problems.

Designed-In High Reliability

A disciplined design methodology is an essential ingredient of manufacturing a reliable part. No amount of finished-product testing can create reliability in a marginal design.

To design-in reliability, Maxim began by formulating a set of physical layout rules that yield reliable products even under worst-case manufacturing tolerances. These rules are rigorously enforced, and every circuit is subjected to computerized Design Rule Checks (DRCs) to ensure compliance.

Special attention is paid to Electrostatic Discharge (ESD) protection. Maxim's goal is to design every pin of every product to withstand ESD voltages in excess of 2000V, through a unique protection structure. In the case of our RS-232 interface circuits, products can even withstand ±15kV ESD using the human-body model, ±8kV ESD using IEC1000-4-2 contact discharge, or ±15kV ESD using IEC1000-4-2 air-gap discharge. Maxim tests each new product for designed 50mA latchup protection.

Designs are extensively simulated (using both circuit and logic simulation software) to evaluate performance under worst-case conditions. Finally, every design is checked and rechecked by independent teams before being released to mask making.

Wafer Inspection

All wafers are fabricated using stable, proven

processes with extremely tight control. Each wafer must pass numerous in-process checkpoints (such as oxide thickness, alignment, critical dimensions, and defect densities), and must comply with Maxim's demanding electrical and physical specifications.

Finished wafers are inspected optically to detect any physical defects. They are then parametrically tested to ensure full conformity to Maxim's specifications. Our parametric measurement system is designed to make the precision measurements that will ensure reliability and reproducibility in analog circuits.

We believe our quality-control technology is the best in the industry, capable of resolving current levels below 1pA, and of producing less than 1pF capacitance. Maxim's proprietary software allows automatic measurement of subthreshold characteristics, fast surface-state density, noise, and other parameters crucial to predicting long-term stability and reliability. Every Maxim wafer is subject to this rigorous screening at no premium to our customers.

Failure-Rate History

The graph below (Figure 8) illustrates Maxim's Failures-in-Time (FIT) rate performance. It also

highlights the progressive improvements made in this FIT rate, a trend that we expect to see continue, thanks to our established continuous-improvement methodology.

Infant Mortality Evaluation

Maxim evaluates each process and product family's Infant Mortality rate immediately after achieving qualified status. Through Infant Mortality analysis, we can identify the common defects for each process or product family. For an illustration of Maxim's low Infant Mortality rate, refer to **Table 2**. **Figure 9** is an Infant Mortality pareto chart showing each category of failures; categories are prioritized based on relative frequency.

____**Reliability Data** Merits of Burn-In

Figure 10 plots Failure Rate versus Time for the metal-gate CMOS process. The plot is based on Table 3's Life Test data and Table 2's Infant Mortality evaluation data, both applied to a General Reliability model. From this data, the benefit of production burn-in can be derived.

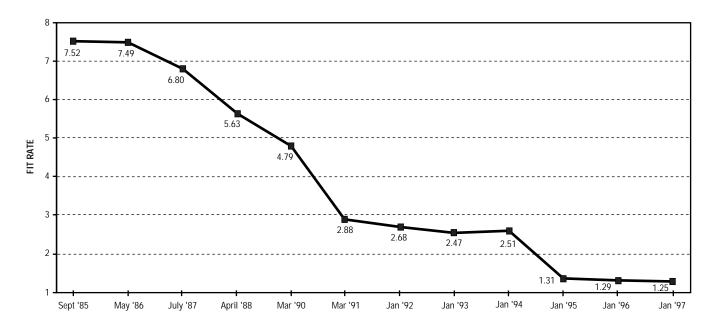


Figure 8. Maxim FIT Rates Over Time

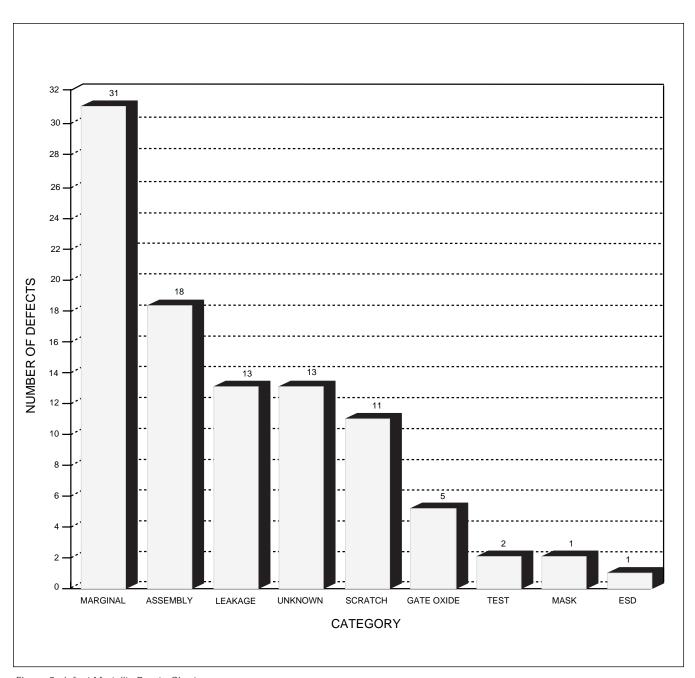


Figure 9. Infant Mortality Pareto Chart

TABLE 2. INFANT MORTALITY EVALUATION RESULTS

DC211CL XECAAS 170			IADLL 2. I	III AIII	MONTALI	L.	ALUATION RESULTS
DC2011-01	PRODUCT	LOT	BI TEMP (°C)	SS	FAILURES	PPM	ANALYSIS
DC2011-01				1	MV1 PR	OCESS	
DG411DY	DG201ACJ DG211CJ DG212CJ DG509ACJ DG508ACJ DG508ACJ	XRCAAB217Q XRCBAA208Q XROCAA045Q XROBAB029Q	135 135 135 135	9642 11,834 12,629 10,216	1 4 2 11 2	85 414 169 871 195	4-MARGINAL LEAKAGE 2-MARGINAL LEAKAGE 7-ISOFF CONTAMINATION, 1-HIGH ICC, 3 TIMING
DG411DY XPIL ANDROIAD 135 10.38 0 0 0 1-MARGINAL LEAKAGE XPILADBOTB 135 10.082 0 0 0 2-MARGINAL LEAKAGE XPILADBOTB 135 10.082 0 0 0 2-MARGINAL LEAKAGE XPILADBOTB 135 10.082 0 0 0 0 0 0 0 0 0	Subtotals			63,931	20	312.8	
Subtotals 135 10,482 0 0 0 2 2 2 2 2 2					MV2 PR	OCESS	
Subtotals 135 10,482 0 0 0 2 2 2 2 2 2	DG411DY	XRI ADB016A	135	10 338	1	97	1-MARGINAL LEAKAGE
CM721BCP XDDCAA096A		XRLADB017B	135	10,482	0	0	
CMT218CIP	Subtotals			30,888	3	97	
ADDIAA097A				•	SMG PR	OCESS	
ICM7218AIP BDDAC20120	ICM7218CIPI ICM7218AIPI ICM7218BIPI	XDDCAA102A XDDAAA097A XDDAAA098A	135 135 135	6824 6694 6927	2 0 0	293 0.0 0.0	1-MARGINAL LEAKAGE, 1-UNKNOWN
CM7218BIPI BDD8C20100	Subtotals			34,290	2	58.3	
MAX1232CPA	ICM7218AIPI ICM7218BIPI	BDDACA015B	135	3101	1	322	1-UNKNOWN
XPPAJO006A 135 12.390 0	Subtotals			27,130	3	110	
MAX232CPE XPWAAA039AA	MAX1232CPA	XPPAJQ003C XPPAJQ006A	135 135	6447 12,390	2 0	310 0.0	1-DIE SCRATCH, 1-PACKAGE CRACK
XPWAA040AA	Subtotals			33,011	2	60.6	
XPWAAA147B	MAX232CPE	XPWAAA040AA XPWAAA044AB XPWAAA048AB XPWAAA050AA	150 150 125 125 150	5627 5831 5575 5768 4643	1 0 2 2 2 3	177.7 0.0 358.7 346.7 646.1	2-BOND WIRE SHORT FAILURES 1-MECHANICAL DAMAGE, 1-GATE-OXIDE DEFECT 1-INTERMITTENT BOND OPEN (HEEL OF WEDGE BOND), 1-GATE-OXIDE DEFECT, 1-MARG. HIGH RIN THRESHOLD (CAUSE UNKNOWN)
XPWBAA012A							
MAX232CPE		XPWBAA012A	150	10,070	3	297.9	1-HIGH I _{EE} GATE-OXIDE DEFECT, 1-HIGH R2 _{IN} RESISTANCE ERR. FUSE BLOWN
MAX690CPA	MAX232CPE MAX202CPE	XKMAAA005Q XKMCAA007A	135 135	15,727 6277	2	127 159	1-T1 _{OUT} STÜCK HIGH UNKNOWN DAMAGE IN FA, 1-R2 _{IN} INPUT THRESHOLD MARG. FAIL 2-UNKNOWN 1-UNKNOWN
MAX690CPA		ANWAAAUUGA	133				1-UNKNOWN
XPYAJA208BA		VDVA 14 200 4	150				1 AC FAILLIDE NO CODATOLI
Subtotals 28,313 10 353.2 MAX1044CPA NEAABZ003B NEAAVN020B 135 3191 0 0 NEAABZ003A 135 5511 2 363 1-UNKNOWN 2-UNKNOWN	I WAXOYUCPA	XPYAJA208BA XPYAJA209A	150 150	4702 9873	3	638.0 303.9	2-MARGINAL HIGH RESET THRESHOLD NO SCRATCH, 1-FUNCTIONAL FAILURE DUE TO DIE SCRATCH 2-DIE SCRATCH ON SILICON SUBSTRATE, 1-DIE SCRATCH ON METAL LINES 1-RESET THRESHOLD DUE TO DIE SCRATCH, 1-MARGINAL IBAT NO SCRATCH,
MAX1044CPA	Out to to!	XFANYS08R	150				
NEAAVN020B NEAABZ003A 135 135 3191 5511 0 2 0 363 2-UNKNOWN				· '			
Subtotals 10,712 3 280	MAX1044CPA	NEAAVN020B	135	3191	0	0	
	Subtotals			10,712	3	280	

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 TABLE 2. INFANT MORTALITY EVALUATION RESULTS (continued)

			1			TION RESULTS (continued)
PRODUCT	LOT	BI TEMP (°C)	SS	FAILURES	PPM	ANALYSIS
		1		SMG PROCES		
MAX667CPA	XEVAJA035A XEVANA046A XEVANB048B	135 135 135	9823 8201 5015	1 5 0	102 610 0	1-PARAMETRIC 1-PARAMETRIC, 4-FUNCTIONAL 1-UNKNOWN
Subtotals			23,039	6	260	
MAX202CPE	NHUABO013A NHUABO007A NHUABO004B	135 135 135	7262 9450 9977	2 2 0	275 212 0	2-FUNCTIONAL, UNKNOWN 1-MASKING DEFECT, 1-UNKNOWN
Subtotals			26,689	4	150	
MAX202ECPE	NDOBCO005A NDOBCO005J NDOBCO006A NDOBCN009A	135 135 135 135	4257 4630 4255 13,440	1 3 0 0	235 648 0 0	1-DIE SCRATCH 1-BAUD CRATER, 2-UNKNOWN
Subtotals			26,582	4	152	
				SG3 PR	OCESS	
MAX485CPA	XKNACA009A XKNACA011A XKNACB016C	135 135 135	8654 9689 6239	1 2 1	115 206 160	1-LEAKAGE 2-UNKNOWN 1-UNKNOWN
Subtotals			24,582	4	162	
MAX705CPA	XTOACZ010A XTOACA014Q XTOACB015B	135 135 135	7026 6759 4895	1 2 0	142 295 0	1-HIGH I _{CC} 2-PARAMETRIC
Subtotals			18,680	3	160	
MAX712CPE MAX713CPE	XAABCA009A XAAACA013A XAAACA016A	135 135 135	12,505 11,873 10,530	3 2 2	239 168 189	3-PARAMETRIC 2-PARAMETRIC 1-FUNCTIONAL, 1-PARAMETRIC
Subtotals			34,908	7	200	
MAX692ACPA	NTABGO01O	135	12,033	2	166	2-PARAMETRIC
Subtotals			12,033	2	166	
MAX488ECPA MAX490ECPA MAX491EEPD MAX489EEPD	XIKGBA037A XIKDBB028C XIKEBB033B XIKHBB036B	135 135 135 135	4590 3347 6470 749	1 0 1 0	217 0 154 0	1-UNKNOWN 1-UNKNOWN
Subtotals			15,156	2	131	
				SG5 PR	OCESS	
MAX232ACPE MAX232ACPE	XETAZZ063Q XETAZZ058Q	135 135	10,016 10,181	6	599 98	2-BOND WIRE SHORT TO DIE EDGE, 1-BOND WIRE SMASH, 1-DIE SCRATCH, 1-HIGH I _{CC} , 1-LOW SLEW RATE 1-OXIDE DEFECT
MAX202ACPE MAX232ACPE	XETAZA075A XETAZA099Q	135 135 135	14,977 10,425	4 3	267 288	2-DIE SCRATCH, 2-UNKNOWN 3-HIGH I _{CC}
Subtotals	VEDALIDOOAA	125	45,599	14	307	2.42-2
MAX452CPA MAX454CPD MAX455CPP	XFPAUB004A XFPAVA011Q XFPAVA009Q	135 135 135	5592 6565 16,236	2 0 5	358 0 308	2-Vos 4-Vos, 1-FUNCTIONAL FAILURE
Subtotals			28,393	7	246.5	
MAX732CPA	XPKABB254A XPKABB261A XPKABB263A	135 135 135	10,848 11,657 12,333	2 1 2	184 86 162	1-AC FAILURE, 1-UNKNOWN 1-AC FAILURE 1-AC FAILURE
Subtotals			34,838	5	143	
		1	ı		ROCESS	
MAX7219CN	BDRAAZ014A BDRAAZ026B BDRAAZ029A	135 135 135	10,091 16,648 11,347	3 3 1	297 180 88	3-UNKNOWN 3-UNKNOWN 1-UNKNOWN
Subtotals			38,086	7	184	
		1	ı	BIP PR	OCESS	1
MAX901BCPE	VWHABB074C VWHABB079D VWHABB083A VWHABB083B	135 135 135 135	4100 4650 6415 4587	1 1 0 2	243 215 0 436	1-LEAKAGE 1-HIGH ICC 2-PARAMETRIC
Subtotals			19,752	4	202	
Combined Totals			704,942	132	187	

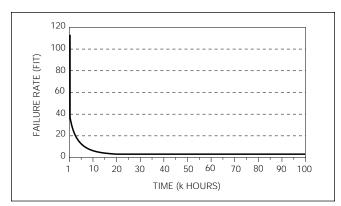


Figure 10. Failure Rate at the Field (55°C for Metal-Gate CMOS Process)

TABLE 3. LIFE TEST RESULT OF MAXIM PRODUCTS FOR EACH PROCESS (Combined Test Conditions: 135°C and 1000 Hrs.)

PROCESS	SAMPLE SIZE	REJECTS	FIT@ 25°C	FIT@ 55°C
SMG	2250	0	0.09	1.59
MV1	385	0	0.54	9.23
MV2	467	0	0.45	7.68
SG3	1602	0	0.13	2.24
SG5	846	1	0.54	9.36
SG1.2	1618	2	0.28	4.89
BIP	1799	1	0.26	4.4
Total	8967	4	0.13	2.3

TABLE 4. LIFE TEST DATA SUMMARY

	NUMBER	NUMBER	TOTAL	DEGREE			FIT @ 25°C	
PRODUCT FAMILY	OF LOTS	OF FAILURES	UNITS TESTED	OF FREEDOM	X ² 60% VALUE	X ² 90% VALUE	60% CONF. LEVEL	90% CONF. LEVEL
Converters (Note 1)	73	11	5399	24	24.7	32.5	1.21	1.60
Linear (Note 2)	251	46	19,530	94	96.4	111.3	1.31	1.51
Timers/Counters/ Display Drivers	3	0	240	2	1.38	3.62	1 .52	4.0
Sum Total of All Product Lots	327	57	25,169	116	118.8	135.3	1.25	1.42

Note 1: A/D Converters, D/A Converters

Note 2: Voltage References, Operational Amplifiers, Power-Supply Circuits, Interface, Filters, Analog Switches, and Multiplexers

Table 3's data summarizes the reliability effect of production burn-in. Essentially, only four units out of 8,967 were found to be outside the specification after 1000 hrs of operation at 135°C. This is equal to an FIT rate of 0.13 at 25°C.

In comparison, the Infant Mortality rate is equal to 132 units out of 704,942 after 12 hrs at 135°C, which has an equivalent FIT rate of approximately 0.794. In practical terms, 0.019%/six years (or 0.003%/year) of the total population would be found as defective through the first six years of operation, with an addi-

tional 0.009%/year failing over the remaining life of the product.

Life Test at 135°C

Life Test is performed using biased conditions that simulate a real-world application. This test estimates the product's field performance. It establishes the constant failure-rate level and identifies any early wearout mechanisms. The tested product is kept in a controlled, elevated-temperature environment, typically at 135°C. This test can detect design, manufacturing, silicon, contamination,

12 ______M/XIM

metal integrity, and assembly-related defects.

Test Used: High-Temperature Life and

Dynamic Life Test (DLT)

Test Conditions: 135°C, 1000 hrs., inputs fed by

clock drivers at 50% duty cycle

Failure Criteria: Must meet data sheet

specifications

Results: See Tables 5–11

Humidity Test

The most popular integrated circuit (IC) packaging material is plastic. Plastic packages are not hermetic; therefore, moisture and other contaminants can enter the package. Humidity testing measures the contaminants present and the product's resistance to ambient conditions. Contaminants can be introduced during both wafer fabrication and assembly, and they can negatively affect product performance. Pressure Pot, 85/85, and HAST tests are used for this evaluation.

85/85 Test

Maxim tests plastic-encapsulated products with an 85/85 test to determine the moisture resistance capability of our products under bias conditions. This test can detect the failure mechanisms found in Life Test. In addition, it can detect electrolytic and chemical corrosion.

Test Used: 85/85

Test Conditions: 85°C, 85% Relative Humidity,

biased, 1000 hrs.

Failure Criteria: Must meet all data sheet

parameters

Results: See **Table 12**

Pressure Pot Test

This test simulates a product's exposure to atmospheric humidity, which can be present during both wafer fabrication and assembly. Although an IC is covered with a nearly hermetic passivation layer (upper-surface coat), the bond pads must be exposed during bonding. Pressure Pot testing quickly determines if a potentially corrosive contaminant is present.

Test Used: Pressure Pot

Test Conditions: 121°C, 100% RH, no bias,

168 hrs.

Failure Criteria: Any opened bond or visual

evidence of corrosion

Results: See **Table 13**

HAST Test

Highly Accelerated Steam and Temperature (HAST) testing is quickly replacing 85/85 testing. It serves the same basic function as 85/85 in typically 10% of the time, making HAST tests useful for immediate feedback and corrective action.

Test Used: HAST

Test Conditions: 120°C, 85% RH, biased,100 hrs.

Failure Criteria: Must meet all data sheet

specifications

Results: See Table 14

Temperature Cycling Test

This test measures a component's response to temperature changes and its construction quality. The test cycles parts through a predetermined temperature range (usually -65°C to +150°C). Both fabrication and assembly problems can be discovered using Temperature Cycling, but the test typically identifies assembly quality.

Test Used: Temperature Cycling

Test Conditions: -65°C to +150°C, 1000 cycles

Failure Criteria: Must meet all data sheet

specifications

Results: See **Table 15**

High-Temperature Storage Life Test

This test evaluates changes in a product's performance after being stored for a set duration (1000 hrs.) at a high temperature (150°C). It is only useful for failure mechanisms accelerated by heat.

Test Used: High-Temperature Storage Life
Test Conditions: 150°C, 1000 hrs. unbiased
Failure Criteria: Must meet all data sheet

specifications

Results: See **Table 16**

_Hybrid Products Reliability Data

Maxim's hybrid product reliability data is presented in **Tables 17** and **18. Table 17** is the Life Test data for products tested in 1996. **Table 18** is the Temperature Cycling test data for hybrid products.

_Process Variability Control

Reliability testing offers little value if the manufacturing process varies widely. A standard assumption, which is often false, is that test samples pulled from production are representative of the total population. Sample variability can be lessened by increasing the number of samples pulled. However, unless a process is kept "in control," major variations can invalidate reliability test results, leading to incorrect

conclusions and diminishing the integrity of failurerate estimates. Uncontrolled processes also make it difficult to prove failure rates of less than 10 FIT.

Maxim monitors the stability of critical process parameters through the use of computerized Statistical Process Control (SPC). Over 125 charts are monitored in-line during wafer production. Additionally, over 100 process parameters are monitored at Wafer Acceptance. Maxim has a target Capability Coefficient (Cpk) goal of 1.5, which is equivalent to 7ppm. In addition to SPC, Maxim uses Design of Experiments (DOE) to improve process capability,

optimize process targeting, and increase robustness.

Reliability Test Results

TABLE 5. LIFE TEST AT 135°C/1000 HRS. FOR THE METAL-GATE CMOS PROCESS (SMG)

DEVICE	DATE	PKG.	SAMPLE	FAII	LURES (F	IRS)
TYPE	CODE	FRG.	SIZE	192	500	1000
MAX634	9551	8 PDIP	77	0	0	0
ICM7555	9551	TO99	77	0	0	0
MAX8211	9552	8 PDIP	77	0	0	0
MAX421	9552	14 PDIP	77	0	0	0
MAX232	9553	16 PDIP	74	0	0	0
MAX232	9602	16 WSO	400	0	0	0
MAX202E	9603	16 PDIP	75	0	0	0
MAX8211	9612	8 SO	77	0	0	0
MAX232	9613	8 SO	77	0	0	0
MAX850	9616	16 PDIP	78	0	0	0
MAX202E	9622	16 PDIP	80	0	0	0
MAX202E	9623	16 PDIP	80	0	0	0
MAX850	9623	8 SO	77	0	0	0
MAX8211	9624	8 SO	77	0	0	0
MAX232	9626	16 PDIP	74	0	0	0
MAX211E	9627	28 SSOP	65	0	0	0
MAX211E	9631	28 SSOP	80	0	0	0
MAX8212	9633	8 SO	77	0	0	0
MAX232	9634	16 PDIP	80	0	0	0
MAX850	9635	8 SO	80	0	0	0
MAX211	9635	28 SSOP	76	0	0	0
MAX844	9636	8 SO	79	0	0	0
MAX232	9638	16 PDIP	77	0	0	0
MAX667	9640	8 PDIP	80	0	0	0
MAX654	9641	14 PDIP	79	0	0	0
Totals			2250	0	0	0

Note: Products included in this Life Test data are: A/D Converters, Operational Amplifiers, Power-Supply Circuits, Interface, and Display Drivers/Counters.

TABLE 6. LIFE TEST AT 135°C/1000 HRS. FOR THE MEDIUM-VOLTAGE METAL-GATE CMOS PROCESS (MV1)

DEVICE	DATE	PKG.	SAMPLE	FAILURES (HRS)		HRS)
TYPE	CODE	PNG.	SIZE	192	500	1000
DG201	9612	16 PDIP	74	0	0	0
DG302	9626	16 PDIP	77	0	0	0
MAX359	9637	16 PDIP	80	0	0	0
DG509	9638	16 PDIP	77	0	0	0
DG301	9638	16 PDIP	77	0	0	0
Totals			385	0	0	0

Note: Products included in this Life Test data are: Analog Switches and Analog Multiplexers.

TABLE 7. LIFE TEST AT 135°C/1000 HRS. FOR THE MEDIUM-VOLTAGE SILICON-GATE CMOS PROCESS (MV2)

DEVICE	DEVICE DATE PKG.		SAMPLE	FAILURES (HRS)			
TYPE	CODE	FRG.	SIZE	192	500	1000	
DG411	9553	16 PDIP	77	0	0	0	
MAX305	9611	16 PDIP	77	0	0	0	
MAX303	9626	16 PDIP	77	0	0	0	
MAX319	9637	8 SO	79	0	0	0	
MAX303	9637	16 PDIP	77	0	0	0	
MAX333	9638	20 PDIP	80	0	0	0	
Totals			467	0	0	0	

TABLE 8. LIFE TEST AT 135°C/1000 HRS. FOR THE 3 μ m SILICON-GATE CMOS PROCESS (SG3)

DEVICE	DATE	PKG.	SAMPLE		URES (H	IRS)
TYPE	CODE	PNG.	SIZE	192	500	1000
MAX708	9551	8 PDIP	79	0	0	0
MAX706	9552	8 PDIP	76	0	0	0
MXD1210	9606	8 PDIP	79	0	0	0
MAX4501	9611	8 PDIP	78	0	0	0
MAX4502	9611	8 PDIP	77	0	0	0
MAX3222	9613	18 PDIP	80	0	0	0
MAX707	9613	8 PDIP	77	0	0	0
MAX4503	9615	8 PDIP	70	0	0	0
MAX4504	9615	8 PDIP	70	0	0	0
MAX4514	9615	8 PDIP	79	0	0	0
MAX4516	9615	8 PDIP	70	0	0	0
MAX4517	9615	8 PDIP	50	0	0	0
MAX4518	9615	14 PDIP	79	0	0	0
MAX4519	9615	14 PDIP	79	0	0	0
MAX4515	9616	8 PDIP	80	0	0	0
MAX797	9616	16 SO	77	0	0	0
MAX785	9623	28 SSOP	65	0	0	0
MAX782	9624	36 SSOP	65	0	0	0
MAX797	9624	16 SO	80	0	0	0
MAX705	9626	8 PDIP	77	0	0	0
MAX785	9630	28 SSOP	38	0	0	0
MAX706	9640	8 PDIP	77	0	0	0
Totals			1602	0	0	0

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TABLE 9. LIFE TEST AT 135°C/1000 HRS. FOR THE 5 μ m SILICON-GATE CMOS PROCESS (SG5)

DEVICE	DATE	PKG.	SAMPLE	FAILURES (HRS)		HRS)	NOTES
TYPE	CODE	FRG.	SIZE	192	500	1000	NOTES
MAX232A	9552	16 PDIP	77	0	0	0	
TSC427	9606	8 PDIP	80	0	0	0	
MAX528	9607	18 PDIP	221	1	0	0	Gate oxide
							defect
MAX232A	9613	16 PDIP	77	0	0	0	
MX7534	9619	20 PDIP	79	0	0	0	
MAX232A	9619	16 PDIP	79	0	0	0	
MAX232A	9629	16 PDIP	77	0	0	0	
MAX232A	9639	16 PDIP	76	0	0	0	
MAX232A	9648	16 PDIP	80	0	0	0	
Totals			846	1	0	0	

Note: Products included in this Life Test data are: A/D Converters, D/A Converters, Interface, and Switched Capacitor Filters.

TABLE 10. LIFE TEST AT 135°C/1000 HRS. FOR THE 1.2µm SILICON-GATE CMOS PROCESS (SG1.2)

DEVICE	DATE	PKG.	SAMPLE	FAIL	JRES (HRS)	NOTES
TYPE	CODE	PNG.	SIZE	192	500	1000	NOTES
MAX619	9546	8 SO	77	0	0	0	
MAX619	9548	8 SO	77	0	0	0	
MAX7219	9553	24 PDIP	77	0	0	0	
MAX7219	9601	24 PDIP	77	0	0	0	
MAX8864S	9601	5 SOT23	69	0	0	0	
MAX8864T	9602	5 SOT23	68	0	0	0	
MAX8863T	9602	5 SOT23	58	0	0	0	
MAX811L	9604	8 PDIP	79	0	0	0	
MAX1600	9613	28 SSOP	77	0	0	1	Mask
							defect
MAX8864S		5 SOT23	68	0	0	0	
MAX8863T	9622	5 SOT23	58	0	0	0	
MAX1247	9624	16 PDIP	51	0	0	0	
MAX7219	9630	24 PDIP	80	0	0	0	
MAX7219	9633	24 PDIP	80	0	0	0	
MAX1600	9633	28 SSOP	75	0	0	0	
MAX1604	9640	28 SSOP	77	0	0	0	
MAX7219	9641	24 PDIP	79	0	0	0	
MAX7219	9642	24 PDIP	77	0	0	0	
MAX7219	9643	24 PDIP	80	0	0	0	
MAX7219	9644	24 PDIP	77	0	0	0	
MAX7219	9645	24 PDIP	77	0	0	0	
MAX7219	9646	24 PDIP	80	1	0	0	Threshold shift
Totals			1618	1	0	1	

TABLE 11. LIFE TEST AT 135°C/1000 HRS. FOR THE BIPOLAR PROCESS (BIPOLAR)

DEVICE	DATE	PKG.	SAMPLE	FAIL	URES (HRS)		NOTES
TYPE	CODE	PNG.	SIZE	192	500	1000	NOTES
MX580	9549	TO52	77	0	0	0	
MAX477	9601	8 PDIP	79	0	0	0	
MXL1013	9603	8 PDIP	80	0	0	0	
MAX400	9604	8 PDIP	77	0	0	0	
MAX471	9607	8 SO	45	0	0	0	
REF02	9608	8 PDIP	77	0	0	0	
MAX471	9609	8 PDIP	80	0	0	0	
MAX724	9612	TO220	80	0	0	0	
MAX872	9612	8 PDIP	76	0	0	0	
MAX4111	9613	8 PDIP	77	0	0	0	
MAX471	9614	8 PDIP	80	0	0	0	
MXL1013	9618	8 PDIP	77	0	0	0	
MAX675	9618	8 PDIP	77	0	0	0	
REF02	9621	8 PDIP	75	0	0	0	
REF02	9623	8 PDIP	73	0	0	0	
MAX872	9624	8 PDIP	80	0	0	0	
MAX471	9625	8 PDIP	73	1	0	0	Lifted bond
MAX492	9627	8 PDIP	80	0	0	0	
MX636	9631	14 PDIP	80	0	0	0	
MAX4102	9637	8 SO	79	0	0	0	
REF02	9638	8 PDIP	77	0	0	0	
MXL1001	964	18 PDIP	20	0	0	0	
Totals			1799	1	0	0	

Note: Products included in this Life Test data are: Voltage References and Operational Amplifiers.

TABLE 12. TEMPERATURE AND HUMIDITY (85/85)
TEST RESULTS

DEVICE	DATE	PKG.	SAMPLE	FAIL	URES (HRS)		NOTES
TYPE	CODE	FKG.	SIZE	192	500	1000	NOTES
MAX619	9546	8 PDIP	73	0	0	0	
MAX921	9547	8 SO	39	0	0	0	
MAX619	9548	8 PDIP	74	0	0	0	
REF01	9550	8 SO	77	0	0	0	
DG411	9553	16 PDIP	77	0	0	0	
MAX8211	9552	8 PDIP	77	0	0	0	
MAX706	9552	8 PDIP	77	0	0	0	
MAX7219	9553	24 PDIP	44	0	0	0	
MAX478	9548	8 SO	42	0	0	0	
MAX202E	9604	16 WSO	26	0	0	0	
MAX7219	9601	24 PDIP	45	0	0	0	
MAX400	9604	8 PDIP	45	0	0	0	
MAX471	9607	8 SO	45	0	0	0	
REF02	9608	8 PDIP	77	0	0	0	
MAX707	9613	8 PDIP	77	0	0	0	
MAX305	9611	16 PDIP	77	0	0	1	Leakage
MAX8211	9612	8 SO	77	0	0	0	
MAX675	9618	8 PDIP	45	0	0	0	
MAX1247	9624	16 PDIP 8 PDIP	77	0	0	0	
REF02	9623		45	-	0	-	
MAX705	9626	8 PDIP 16 PDIP	77 77	0	0	0	III ah hiaa
MAX303	9626	16 PDIP	//	U	U		High bias current
MAX8211	9624	8 SO	76	0	0	0	Current
MAX8212	9636	8 SO	38	0	0	0	
MAX692	9637	8 SO	45	0	0	ő	
MAX8212	9633	8 SO	77	_	-	Ö	
MAX706	9640	8 PDIP	77			Ö	
MAX303	9637	16 PDIP	72			Ö	
REF02	9638	8 PDIP	45			0	
Totals			1800	0	0	2	

DEVICE

TYPE

MX7574 MAX619

MAX619 MAX478 MAX246 MAX245 MAX247 REF01 MAX8211 MAX706 DG411 MAX232 MAX7219 DG303 MAX726 MAX7219 MAX1600 MAX232 MAX8863T MAX8864S MAX202E MAX400 MAX811L MAX471 MAX850 MAX232A MAX850 MAX8211 MAX809L MAX8864T MAX305 MAX471 MAX872 MAX786 REF02 MAX232 MAX707 DG201 MAX809L MAX724 MAX809L MAX243 MXL1013 MAX675 MAX243 MAX511 REF02 MAX8864S

MAX8863T MAX4501 REF02 MAX1247

MAX8211 MAX872 MAX471 MAX232A

Product Reliability Report

TABLE 13. PRESSURE POT TEST AT 121°C/100% RH 15 PSIG/168 HRS. (ALL PLASTIC PACKAGES)

DATE CODE	PKG.	SAMPLE SIZE	FAILURES (HRS) 168	NOTES
9528 9546 9548 9548 9549 9549 9550 9552 9553 9553 9601 9601 9602 9602 9602 9603 9604 9604 9604 9607 9608 9611 9611 9611 9612 9612 9612 9612 9613 9613 9613 9613 9614 9615 9618 9618 9619 9619 9619 9619 9619 9619	16 PDIP 8 SO 8 SO 8 SO 40 PDIP 40 PDIP 40 PDIP 8 SO 8 PDIP 16 PDIP 16 PDIP 16 PDIP 16 WSO 16 WSO 15 SOT23 16 PDIP 8 PDIP 16 PDIP 17 SOT23 18 PDIP 16 PDIP 18 PDIP 19 SOT23 10 SOT23 11 SOT23 12 SOT23 13 SOT23 14 SO 15 SOT23 16 PDIP 16 PDIP 17 SOT23 18 PDIP 18 PDIP 19 SOT23 10 SOT23 11 SOT23 12 SOT23 13 SOT23 14 SO 15 SOT23 16 SO 16 PDIP 17 SOT23 18 PDIP 18 SOT23 18 PDIP 19 SOT23 18 PDIP 18 PDIP 18 SOT23 18 PDIP 18 SOT23 18 PDIP 1	45 45 45 45 45 45 45 45 45 45 45 45 45 4		

TABLE 13 (continued)

TABLE 10 (continued)									
DEVICE TYPE	DATE CODE	PKG.	SAMPLE SIZE	FAILURES (HRS) 168	NOTES				
MAX232 MAX705 DG302 MAX303 MAX809L MAX492 MAX1630 MAX211E MAX809L MAX232A MAX232A MAX232A MAX232A MAX2321 MAX203 MAX211 MX7226 MAX487 MAX211 MX7226 MAX487 MAX211 MX7226 MAX487 MAX212 MAX232 MAX232 MAX212 MAX232 MAX487 MAX212 MAX487 MAX212 MAX487 MAX492 MAX492 MAX492 MAX492 MAX203 MAX797 MAX232 MAX232 MAX232 MAX232 MAX232 MAX492	9626 9626 9626 9626 9627 9627 9627 9628 9629 9630 9633 9633 9635 9636 9636 9636 9636 9636	16 PDIP 8 PDIP 16 PDIP 16 PDIP 28 SSOP 28 SSOP 3 SOT23 16 PDIP 16 SO 24 PDIP 18 PDIP 8 SO 20 WSO 28 SSOP 20 WSO 8 PDIP 8 SO 16 PDIP 8 PDIP 16 SO 16 PDIP 8 PDIP 16 SO 16 PDIP 18 PDIP 18 PDIP 18 PDIP	45 45 45 45 45 45 45 45 45 45 45 47 77 45 45 45 45 47 47 45 45 47 47 45 45 47 47 47 47 47 47 47 47 47 47 47 47 47	0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	High input offset				
MAX817L MAX1604 MAX232A MAX706 MAX1604 MAX782 MAX7219 MAX7219 MAX7219 MAX235 MAX211 MAX235 MAX235 MAX235 MAX235	9639 9640 9640 9640 9640 9641 9642 9643 9644 9644 9645 9645	8 PDIP 28 SSOP 16 SO 8 PDIP 28 SSOP 36 SSOP 24 PDIP 16 SO 24 PDIP 24 PDIP 28 SSOP 29 PDIP 20 PDIP 20 PDIP 21 PDIP 22 PDIP 24 PDIP 24 PDIP 25 PDIP 26 PDIP 27 PDIP 28 SSOP 29 PDIP	77 77 45 45 77 80 77 77 77 77 77 77 77 77	0 0 0 0 0 0 0 0 0 0 0	voltage Capacitor open				
MAX233 MAX233A MAX233A	9646 9649 9650	20 DIP 20 WSO 20 WSO	77 77 77	0 0 0					
Totals			6167	2					

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TABLE 14. HAST TEST RESULTS 120°C/85% RH/BIASED/100 HRS.

DEVICE SAMPLE FAILURES (HRS) DATE PKG. NOTES **TYPE** CODE SIZE 100 MAX8864S 5 SOT23 MAX232 9602 16 WSO 25 0 MAX8864T 9602 5 SOT23 25 0 MAX8863T 9602 SOT23 25 0 MAX811 9604 8 PDIP 25 0 MX636 9607 16 WSO 25 MX636 14 PDIP 25 0 9611 DG201 16 PDIP 25 0 9612 MAX724 TO220 25 0 9612 8 PDIP 25 0 MAX872 9612 MAX471 9614 8 PDIP 25 0 25 0 MAX786 9617 28 SSOP MAX4123 9618 8 SO 25 0 MAX4125 8 SO 9620 25 0 25 MAX202 16 WSO 0 9620 MAX8864S 5 SOT23 9621 25 Ω MAX8863T 5 SOT23 25 9622 0 5 SOT23 25 Õ MAX4501 9622 8 PDIP MAX872 25 0 9624 MAX471 9625 8 PDIP 25 0 24 PDIP 25 MAX235 9626 8 PDIP 23 0 MAX492 9627 28 SSOP 25 0 MAX211E 9627 16 PDIP MAX232A 9629 25 0 25 MAX233A 9629 20 PDIP 0 MAX203 9635 20 WSO 25 0 MAX211 9635 28 SSOP 25 0 MAX488 9636 8 SO 25 0 MAX203 9637 20 WSO 25 1 Capacitor 0 MAX232 9638 16 PDIP 25 MAX232A 9639 16 PDIP 25 0 MAX203 9640 20 WSO 25 0 MAX235 9644 24 PDIP 25 0 MAX7219 9645 24 PDIP 25 0 MAX235 9645 24 PDIP 25 0 MAX235 9646 24 PDIP 25 0 MAX7219 9646 24 PDIP 24 0 MAX233A 9651 20 WSO 25 0 1 946 Totals

TABLE 15. TEMPERATURE CYCLING -65°C TO +150°C 1000 CYCLES (ALL PACKAGE TYPES)

DEVICE	DATE	BIG 5	SAMPLE	FAIL	IRS)	
TYPE	CODE	PKG.	SIZE	168	168	168
TYPE MAX619 MAX619 MAX478 MX580 REF01 ICM7555 MAX8211 MAX232A MAX706 MAX421 DG411 MAX203 MAX7219 DG303 MAX7219 MAX8864S MAX232 MAX8864S MAX232 MAX8864T MAX8863T MAX202E MAX202E MAX400 MAX811L MAX471	9546 9548 9548 9549 9550 9551 9552 9552 9552 9553 9553 9601 9601 9601 9602 9602 9602 9604 9604	8 SO 8 SO 8 SO TO52 8 SO TO99 8 PDIP 16 PDIP 16 PDIP 16 PDIP 16 PDIP 16 WSO 24 PDIP 16 WSO 24 PDIP 16 WSO 25 SOT23 5 SOT23 16 WSO 5 SOT23 16 PDIP 16 WSO 8 PDIP 8 PDIP 8 SO 8 PDIP 8 PDIP 8 SO 8 PDIP 8 PDIP 8 SO 8 PDIP 8 SO 8 PDIP 8 PDIP 8 SO 8 PDIP 8 SO 8 PDIP 8 PDIP 8 PDIP 8 SO 8 PDIP 8 PDIP	74 75 45 45 77 77 77 77 45 77 45 77 45 47 77 45 47 77 445 47 47 44 460 45 44	168 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	168 0 0 0 0 0 0 0 0 0 0 0 0 0
REF02 MAX305 MAX809L DG201 MAX8211 MAX724 MAX872 MAX232A MAX232 MAX707 MAX471 MAX809L MXL1013 MAX675 REF02 MAX8864S MAX8863T MAX4501 REF02 MAX1247 MAX8211 MAX872	9608 9611 9611 9612 9612 9612 9613 9613 9613 9614 9614 9618 9621 9621 9622 9622 9623 9624	8 PDIP 16 PDIP 3 SOT23 16 PDIP 8 PDIP TO220 8 PDIP 16 PDIP 16 PDIP 8 PDIP 3 SOT23 8 PDIP 8 PDIP 8 PDIP 8 PDIP 5 SOT23 5 SOT23 5 SOT23 5 SOT23 5 SOT23 8 PDIP 16 PDIP 8 SO 8 PDIP	77 77 44 77 77 77 77 77 77 77 77 44 45 44 47 72 77 44 45 77 77 77			
MAX471 MAX232 MAX705 DG302 MAX303 MAX492 MAX1630 MAX232A MX636 MAX8212 MAX211 MAX488 DG301 MAX692A MAX303 MAX232 REF02 MAX232A MAX492 MAX7219 MAX7219	9625 9626 9626 9626 9626 9627 9627 9631 9633 9635 9636 9637 9638 9639 9639 9640 9644 9644	8 PDIP 16 PDIP 8 PDIP 16 PDIP 8 PDIP 28 SSOP 16 PDIP 8 SO 28 SSOP 8 SO 16 PDIP 8 SO 16 PDIP 8 PDIP 8 PDIP 9 PDIP 8 PDIP 16 PDIP 9 PDIP 16 PDIP 17 PDIP 18 PDIP 18 PDIP 19 PDIP 10 PDIP	77 77 77 77 77 77 45 77 77 76 45 77 77 77 45 77 77 45 77 77 45 47 45 47 45 45 45 45 45			
Totals			4436	0	0	0

TABLE 16. HIGH-TEMPERATURE STORAGE LIFE TEST 150°C/1000 HRS. (ALL PACKAGE TYPES)

LIFE IES	1 150°C	3/1000 HRS	o. (ALL P	ACKA	GEIY	PES)
DEVICE	DATE	BICO	SAMPLE	FAII	URES (H	IRS)
TYPE	CODE	PKG.	SIZE	192	500	1000
MAX3480	9538	28 PDIP	45	0	0	0
MAX619	9548	8 SO	77	0	0	0
MAX478	9548	8 SO	43	0	0	0
MX580	9549	TO52	45	0	0	0
REF01	9550	8 SO	45	0	0	0
MAX634	9551	8 PDIP	45	0	0	0
ICM7555	9551	TO99	45	0	0	0
MAX8211	9552	8 PDIP	45	0	0	0
MAX232A	9552	16 PDIP	45	0	0	0
MAX706 MAX421	9552 9552	8 PDIP 14 PDIP	45 45	0	0	0
DG411	9553	16 PDIP	45	0	0	0
MAX232	9553	16 PDIP	45	0	0	l ő
MAX7219	9553	24 PDIP	45	Ö	ő	Ö
DG303	9601	16 WSO	45	ō	Ö	Ö
MAX7219	9601	24 PDIP	45	0	0	0
MAX8864S	9601	5 SOT23	45	0	0	0
MAX8864T	9602	5 SOT23	44	0	0	0
MAX8863T	9602	5 SOT23	42	0	0	0
MAX202E	9603	16 PDIP	45	0	0	0
MAX202E	9604	16 WSO	45	0	0	0
MAX400	9604	8 PDIP 8 PDIP	45 45	0	0	0
MAX811L MAX471	9604 9607	8 SO	45 45	0	0	0
REF02	9608	8 PDIP	45	0	0	0
MAX305	9611	16 PDIP	43	0	0	0
DG201	9612	16 PDIP	45	ő	Ö	ő
MAX8211	9612	8 SO	45	0	0	O
MAX724	9612	TO220	45	0	0	0
MAX872	9612	8 PDIP	45	0	0	0
MAX232A	9613	16 PDIP	45	0	0	0
MAX232	9613	16 PDIP	45	0	0	0
MAX707	9613	8 PDIP	45	0	0	0
MAX471 MAX233A	9614	8 PDIP	45 14	0	0	0
MAX233A	9617 9618	20 WSO 20 WSO	14	0	0	0
MAX675	9618	8 PDIP	45	0	0	0
REF02	9621	8 PDIP	44	Ö	ő	l ő
MAX8864S	9621	5 SOT23	73	0	0	0
MAX8863T	9622	5 SOT23	42	0	0	0
REF02	9623	8 PDIP	45	0	0	0
MAX8211	9624	8 SO	45	0	0	0
MAX872	9624	8 PDIP	45	0	0	0
MAX471	9625	8 PDIP	45	0	0	0
MAX705 DG302	9626 9626	8 PDIP 16 PDIP	45 45	0	0	0
MAX303	9626	16 PDIP	45	0	0	0
MAX492	9627	8 PDIP	45	ő	0	Ö
MAX232A	9629	16 PDIP	45	Ō	Ö	Ō
MAX8212	9633	8 SO	45	0	0	0
MAX203	9635	20 WSO	45	0	0	0
MAX211	9635	28 SSOP	45	0	0	0
DG301	9636	16 PDIP	45	0	0	0
MAX203	9637	20 WSO	45	0	0	0
MAX303	9637	16 PDIP	41	0	0	0
MAX232 REF02	9638	16 PDIP 8 PDIP	45 45	0	0	0
MAX233	9638 9638	20 PDIP	45 45	0	0	0
MAX232A	9639	16 PDIP	45	0	0	0
MAX706	9640	8 PDIP	45	ő	0	Ö
MAX203	9640	20 WSO	45	Ö	0	ő
MAX233	9641	20 PDIP	45	Ö	Ō	ō
MAX7219	9644	20 PDIP	45	0	0	0
MAX681	9644	14 PDIP	77	0	0	0
MAX235	9644	24 PDIP	45	0	0	0

TABLE 16 (continued)

DEVICE	DATE	PKG.	SAMPLE	SAMPLE FAILURE		ES (HRS)	
TYPE	CODE	FNG.	SIZE	192	500	1000	
MAX211	9644	28 SSOP	45	0	0	0	
MAX203	9644	20 PDIP	45	0	0	0	
MAX203	9645	20 PDIP	45	0	0	0	
MAX235	9645	24 PDIP	45	0	0	0	
MAX235	9646	24 PDIP	44	0	0	0	
MAX7219	9646	24 PDIP	45	0	0	0	
MAX233	9646	20 PDIP	45	0	0	0	
Totals			3253	0	0	0	

TABLE 17. HYBRID PRODUCTS LIFE TEST 135°C/1000 HRS

DEVICE TYPE	DATE	PKG.	SAMPLE	FAII	URES (F	IRS)
DEVICE TIPE	CODE	rko.	SIZE	192	500	1000
MAX246	9549	40 PDIP	75	0	0	0
MAX245	9549	40 PDIP	77	0	0	0
MAX247	9549	40 PDIP	75	0	0	0
MAX233A	9617	20 WSO	63	0	0	0
MAX233A	9618	20 WSO	63	0	0	0
MAX203	9635	20 WSO	77	0	0	0
MAX233	9638	20 PDIP	77	0	0	0
MAX203	9640	20 WSO	77	0	0	0
MAX233	9641	20 PDIP	77	0	0	0
MAX681	9644	14 PDIP	76	0	0	0
MAX235	9644	24 PDIP	77	0	0	0
MAX203	9644	20 PDIP	77	0	0	0
MAX203	9645	20 PDIP	76	0	0	0
MAX235	9645	24 PDIP	76	0	0	0
MAX235	9646	24 PDIP	77	0	0	0
MAX233	9646	20 PDIP	77	0	0	0
Totals			1197	0	0	0

TABLE 18. HYBRID PRODUCTS TEMPERATURE CYCLING -65°C TO +150°C/1000 CYCLES

DEVICE TYPE	DATE	PKG.	SAMPLE	FAILURES (H		IRS)
DEVICE ITPE	CODE	PNG.	SIZE	200	500	1000
MAX3480	9538	28 PDIP	45	0	0	0
MAX252	9543	40 PDIP	44	0	0	0
MAX625	9544	24 PDIP	45	0	0	0
MAX246	9549	40 PDIP	77	0	0	0
MAX245	9549	40 PDIP	75	0	0	0
MAX247	9549	40 PDIP	75	0	0	0
MAX233A	9617	20 WSO	74	0	0	0
MAX233A	9618	20 WSO	77	0	0	0
MAX203	9635	20 WSO	43	0	0	0
MAX203	9637	20 WSO	43	0	0	0
MAX233	9638	20 PDIP	77	0	0	0
MAX203	9640	20 WSO	45	0	0	0
MAX233	9641	20 PDIP	77	0	0	0
MAX681	9644	16 PDIP	77	0	0	0
MAX235	9644	24 PDIP	76	0	0	0
MAX203	9644	20 PDIP	77	0	0	0
MAX203	9645	20 PDIP	77	0	0	0
MAX235	9645	24 PDIP	77	0	0	0
MAX235	9646	24 PDIP	76	0	0	0
MAX233	9646	20 PDIP	77	0	0	0
Totals			1334	0	0	0

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Appendix 1: Determining Acceleration Factor

Definition of Terms

An acceleration factor is a constant used in reliability prediction formulas that expresses the enhanced effect of temperature on a device's failure rate. It is usually used to show the difference (or acceleration effect) between the failure rate at two temperatures. In simple terms, a statement such as, "The failure rate of these devices operating at 150°C is five-times greater than the failure rate at 25°C," implies an acceleration factor of 5.

The acceleration factor used in the semiconductor industry is a result of the Arrhenius equation stated below:

Where:

Acceleration Factor =
$$Ke^{\frac{Ea}{k}} \left(\frac{1}{T_1} - \frac{1}{T_2}\right)$$

K = an experimentally determined constant

Ea = the activation energy

k = Boltzmann's constant

 T_1 = actual use temp. in degrees Kelvin

 T_2 = test temp. in degrees Kelvin

How to Use the Arrhenius Equation

The first step in using the Arrhenius equation given above is to determine an activation energy (Ea), which may be done in one of two ways.

The first method involves using failure analysis techniques to determine the actual failure mechanism. The activation energies for many failure mechanisms have already been determined, and tabulated in published literature. Although all processes are not exactly the same, the activation energy of a particular failure mechanism is mainly determined by physical principles. A published activation energy will not be the exact figure associated with a particular process, but it will be a very close approximation.

The dominant failure mechanisms in Maxim's Life Tests have activation energies in the range of 0.8eV to 1.2eV. We have conservatively chosen 0.8eV for the purposes of computing the acceleration factors used in this report. Actual acceleration factors are

probably greater than those quoted.

The second method of determining an activation energy is empirical. Two groups of devices are tested at different temperatures, and the difference between their failure rates is measured. An example is shown below:

Group 1 = 9822 failures after 100 hrs. of operation at 150°C.

Group 2 = 1 failure after 100 hrs. of operation at 25°C.

The acceleration factor for this particular failure mechanism between these two temperatures is, therefore, 9822.

Where:

$$9822 = e^{\frac{Ea}{k} \left(\frac{1}{T_1} - \frac{1}{T_2} \right)}$$

Ea = the unknown activation energy

 $k = 8.63 \times 10^{-5} \text{eV}/^{\circ} \text{K}$

 $T_1 = 25^{\circ}C + 273^{\circ}C \text{ or } 298^{\circ}K$

 $T_2 = 150^{\circ}C + 273^{\circ}C \text{ or } 423^{\circ}K$

Substituting:

$$9822 = e^{\frac{Ea}{8.63 \times 10^{-5}} \left(\frac{1}{298} - \frac{1}{423} \right)}$$

$$9822 = e^{Ea} \times 11.49$$

Taking the natural log of both sides:

$$Log_e 9822 = Ea \times 11.49$$

$$\frac{\text{Log}_{e}9822}{11.49}$$
 = Ea

Therefore, Ea = 0.8eV

Assuming that this activation energy represents the dominant failure mechanism of the device under consideration, it may then be used to determine the acceleration factor between any two temperatures as follows:

Between 150°C and 70°C, for example:

Acceleration Factor = e
$$\frac{0.8}{8.63 \times 10^{-5}} \left(\frac{1}{T_1} - \frac{1}{T_2} \right)$$

Where:

$$T_1 = 70$$
°C + 273°C = 343°K
 $T_2 = 150$ °C + 273°C = 423°K

Substituting for $T_1 + T_2$ and solving for e yields the result:

Acceleration Factor = 165

The acceleration factor between 150°C and 70°C is 165.

Appendix 2: Determining Failure Rate

Definition of Terms

The Mean Time Between Failures (MTBF) is the average time it takes for a failure to occur. For example, assume a company tests 100 units for 1000 hrs. The total device-hours accrued would be 100 x 1000, or 100,000 device-hours. Now assume two units were found to be failures. Roughly, it could be said that the MTBF would equal:

$$MTBF = \frac{Total\ Device\ Hrs.}{Total\ No.\ of\ Failures} = \frac{100,000}{2} = 50,000\ hrs.$$

The Failure Rate (FR) is equal to the reciprocal of the MTBF, or:

$$FR = \frac{1}{MTBF} = \frac{1}{50,000} = 0.00002$$

If this number is multiplied by 1 x 10^5 , the failure rate in terms of percent per 1000 hrs. is obtained; i.e., 2%.

A common reliability term also used to express the failure rate is Failures-in-Time, or FIT. This is the number of failures per billion device-hours, and is obtained by dividing the Failure Rate by 10-9:

$$\frac{FR}{10^{-9}} = FIT.$$

Using the above example:

$$FIT = 0.00002/10^{-9}$$
= 20.000

The FIT rate is, therefore, shorthand for the number of units predicted to fail in a billion (10-9) device-hours at the specified temperature.

Calculating Failure Rates and FITs

The failure rate can be expressed in terms of the following four variables:

A = The number of failures observed after test

B = The number of hours the test was run

C = The number of devices used in the test

D = The temperature acceleration factor (see Appendix 1)

Using data in **Table 2**, a failure rate at 25°C can now be calculated:

A = 57

B = 192

C = 25,169

D = 9822 (Assuming Ea = 0.8eV, and a test temperature of 150°C)

Substituting:

$$FR = \frac{57}{192 \times 25,169 \times 9822} = 1.20 \times 10^{-9}$$

Expressing this in terms of the FIT rate:

$$FIT = 1.20$$

To determine the FIT rate at a new temperature, the acceleration factor (D) must be recalculated from the Arrhenius equation given in Appendix 1.

Including Statistical Effects in the FIT Calculation

Because a small random sample is being chosen from each lot, the statistical effects are significant enough to mention. With most published failure rate figures, there is an associated confidence level number. This number expresses the confidence level that the actual failure rate of the lot will be equal to or lower than the predicted failure rate.

The failure rate calculation, including a confidence level, is determined as follows:

$$FR = \frac{X^2}{2DH}$$

Where:

 X^2 = the Chi square value

2DH = 2 times the total device hours

$$= 2 \times (B \times C \times D)$$

The Chi square value is based on a particular type of statistical distribution. However, all that is required to arrive at this value is knowing the number of failures. In this example, there were 57 failures. The Chi square value is found using a standard X^2 distribution table. The tabular values are found using the factors (1 - CL), where CL is the desired confidence level, and 2(N+1) is the degree of freedom.

The value of (1 - CL) for a 60% confidence level is (1 - 0.60) = 0.40.

The number of degrees of freedom is 2(57 + 1) = 116.

The Chi square value found under the values of 0.40 and 116 degrees of freedom is 119.

Therefore, the failure rate found using a 60% confidence level is:

$$FR = \frac{119}{9.49 \times 10^{10}} = 1.25 \times 10^{-9}$$

Expressed as Failure-in-Time rate:

$$FIT = 1.25$$

Referring to **Table 2**, one can see that for Maxim's product, there is a 60% confidence level that no more than 1.25 units will fail per billion (10⁹) device-hours of operation at 25°C.

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